

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	608	((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact	US-PGPUB; USPAT	OR	ON	2005/09/23 08:52
L3	399	((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130"	US-PGPUB; USPAT	OR	ON	2005/09/23 08:53
L4	388	((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130" and semiconductor	US-PGPUB; USPAT	OR	ON	2005/09/23 08:54
L5	1319	(438/197).CCLS.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/09/23 08:54
L6	7	438/197.ccls. and ((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130" and semiconductor	US-PGPUB; USPAT	OR	ON	2005/09/23 08:55
L7	7	438/197.ccls. and ((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130" and semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 09:51
L8	210	"438"/\$.ccls. and ((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130" and semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 09:57
L9	332	"257"/\$.ccls. and ((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130" and semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 09:55
L11	8	(("6413802") or ("20040062501") or ("4,844,604") or ("5,881,194") or ("5,908,873") or ("6,187,835") or ("6,197,422") or ("6,130,980"))).PN.	US-PGPUB; USPAT	OR	OFF	2005/09/23 10:02

L14	332	"257"/\$.ccls. and ((vertical adj transistor adj structure) or ("FIN")) and (lithograp\$4) and gate and contact and @ad<="20030130" and semiconductor	US-PGPUB; USPAT	OR	ON	2005/09/23 09:55
L15	62	"438"/\$.ccls. and ((fin adj field adj effect\$3 adj transistor) or ("finfet")) and @ad<="20030130" and semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 09:59
L16	105	"257"/\$.ccls. and ((fin adj field adj effect\$3 adj transistor) or ("finfet")) and @ad<="20030130" and semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 09:59
L17	1	("20050014318").PN.	US-PGPUB; USPAT	OR	OFF	2005/09/23 10:02